

**60 V, 100 A, 3.8 mΩ Low $R_{DS(ON)}$
N ch Trench Power MOSFET
2SK4161D**



Features

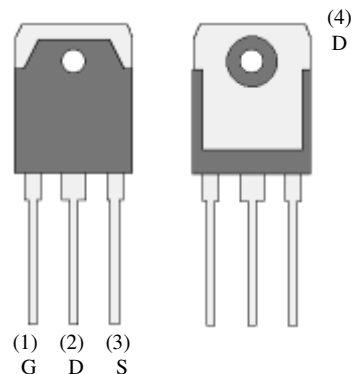
- $V_{(BR)DSS}$ -----60 V ($I_D = 100 \mu A$)
- I_D ----- 100 A
- $R_{DS(ON)}$ -----4.8 mΩ max. ($I_D = 35 A, V_{GS} = 10 V$)
-
- AEC-Q101 Qualified
- 175°C Capability
- Low On Resistance
- ESD Protection Zener on Gate
- 100% Avalanche Tested
- Compliant with RoHS directive

Applications

- Electric power Steering (EPS)
- Motor
- DC/DC Converter
- Other Switching Mode Power Supply, SMPS

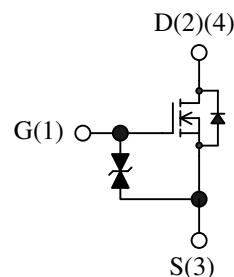
Package

TO3P-3L



Not to scale

Equivalent circuit



Absolute Maximum Ratings

Unless otherwise specified, $T_A = 25 \text{ }^\circ\text{C}$

Parameter	Symbol	Test conditions	Rating	Unit
Drain to Source Voltage	V_{DS}		60	V
Gate to Source Voltage	V_{GS}		± 20	V
Continuous Drain Current	I_D	$T_C = 25 \text{ }^\circ\text{C}$	100	A
Pulsed Drain Current	I_{DM}	$PW \leq 100\mu s$ Duty cycle $\leq 1 \%$	200	A
Continuous Source Current (Body Diode)	I_S	$T_C = 25 \text{ }^\circ\text{C}$	100	A
Pulsed Source Current (Body Diode)	I_{SM}	$PW \leq 100\mu s$ Duty cycle $\leq 1 \%$	200	A
Single Pulse Avalanche Energy	E_{AS}	$V_{DD} = 20 V, L = 1 mH,$ $I_{AS} = 20 A, \text{ unclamped,}$ Refer to Figure 1	400	mJ
Power Dissipation	P_D	$T_C = 25 \text{ }^\circ\text{C}$	132	W
Operating Junction Temperature	T_J		175	$^\circ\text{C}$
Storage Temperature Range	T_{STG}		- 55 to 175	$^\circ\text{C}$

Thermal Characteristics

Unless otherwise specified, $T_A = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Thermal Resistance (Junction to Case)	$R_{\theta JC}$		–	–	1.13	$^\circ\text{C}/\text{W}$
Thermal Resistance (Junction to Ambient)	$R_{\theta JA}$		–	–	35.7	$^\circ\text{C}/\text{W}$

Electrical Characteristics

Unless otherwise specified, $T_A = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 100\text{ }\mu\text{A}$, $V_{GS} = 0\text{ V}$	60	–	–	V
Drain to Source Leakage Current	I_{DSS}	$V_{DS} = 60\text{ V}$, $V_{GS} = 0\text{ V}$	–	–	100	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS} = \pm 15\text{ V}$	–	–	± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = 10\text{ V}$, $I_D = 1\text{ mA}$	3.0	3.6	4.0	V
Static Drain to Source On-Resistance	$R_{DS(on)}$	$I_D = 35\text{ A}$, $V_{GS} = 10\text{ V}$	–	3.8	4.8	$\text{m}\Omega$
		$I_D = 35\text{ A}$, $V_{GS} = 8\text{ V}$	–	4.2	6.0	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = 10\text{ V}$ $V_{GS} = 0\text{ V}$ $f = 1\text{ MHz}$	–	10000	–	pF
Output Capacitance	C_{oss}		–	1000	–	
Reverse Transfer Capacitance	C_{rss}		–	730	–	
Total Gate Charge ($V_{GS} = 10\text{ V}$)	Q_{gl}	$V_{DS} = 40\text{ V}$ $I_D = 40\text{ A}$	–	145	–	nC
Gate to Source Charge	Q_{gs}		–	40	–	
Gate to Drain Charge	Q_{gd}		–	35	–	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 20\text{ V}$ $I_D = 40\text{ A}$ $V_{GS} = 10\text{ V}$, $R_G = 30\text{ }\Omega$ Refer to Figure 2	–	160	–	ns
Rise Time	t_r		–	490	–	
Turn-Off Delay Time	$t_{d(off)}$		–	400	–	
Fall Time	t_f		–	200	–	
Source to Drain Diode Forward Voltage	V_{SD}	$I_S = 50\text{ A}$, $V_{GS} = 0\text{ V}$	–	0.9	1.2	V
Source to Drain Diode Reverse Recovery Time	t_{rr}	$I_F = 25\text{ A}$ $di/dt = 50\text{ A}/\mu\text{s}$ Refer to Figure 3	–	50	–	ns

Test Circuits and Waveforms

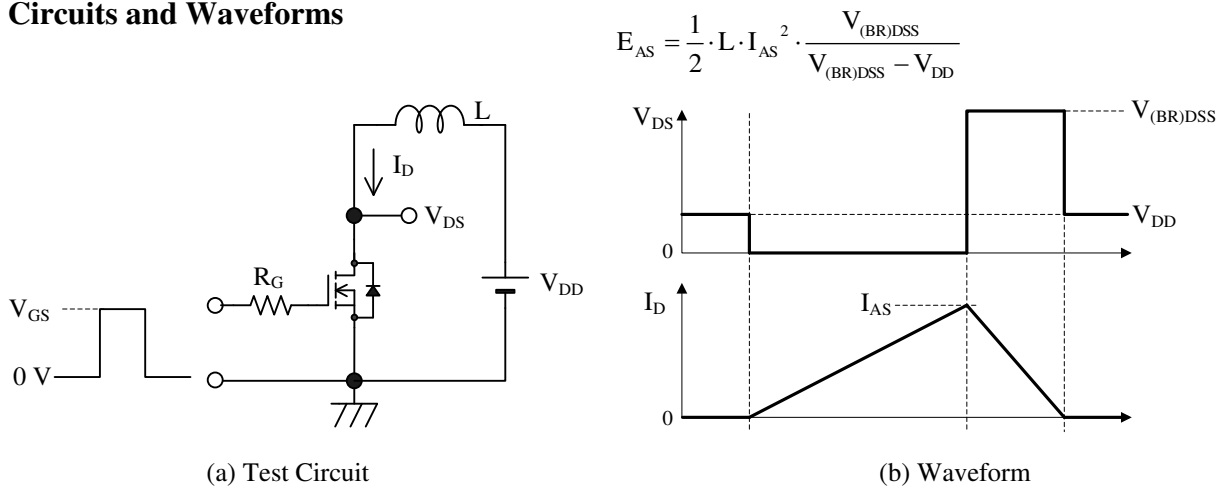


Figure 1 Unclamped Inductive Switching

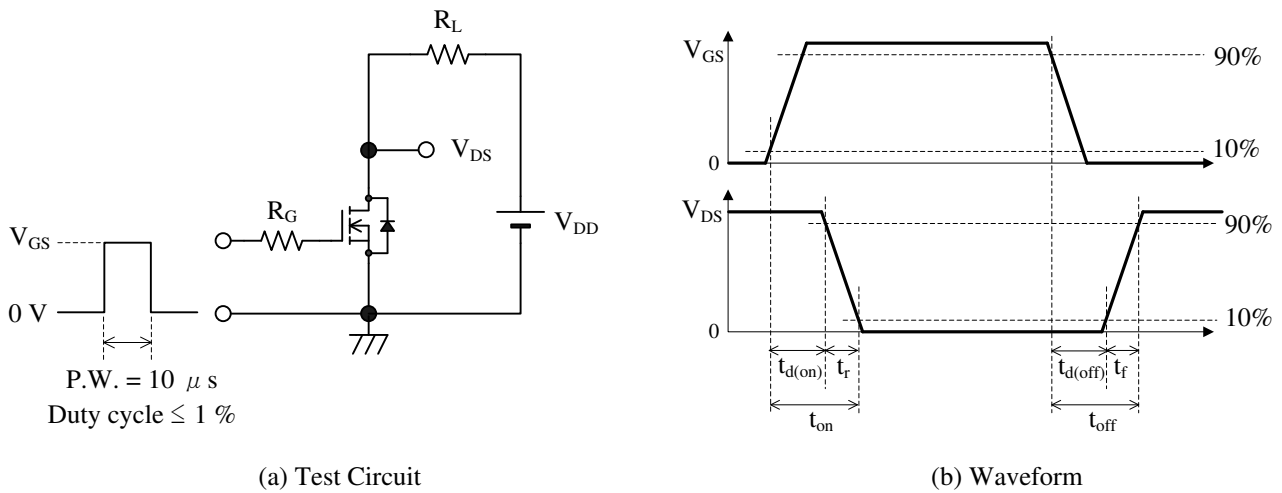


Figure 2 Switching Time

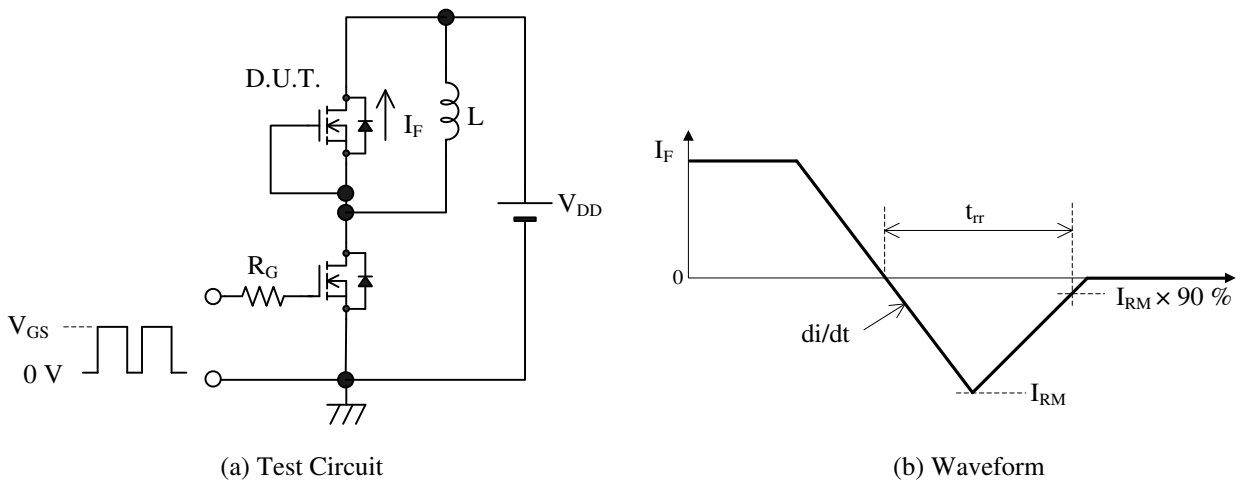
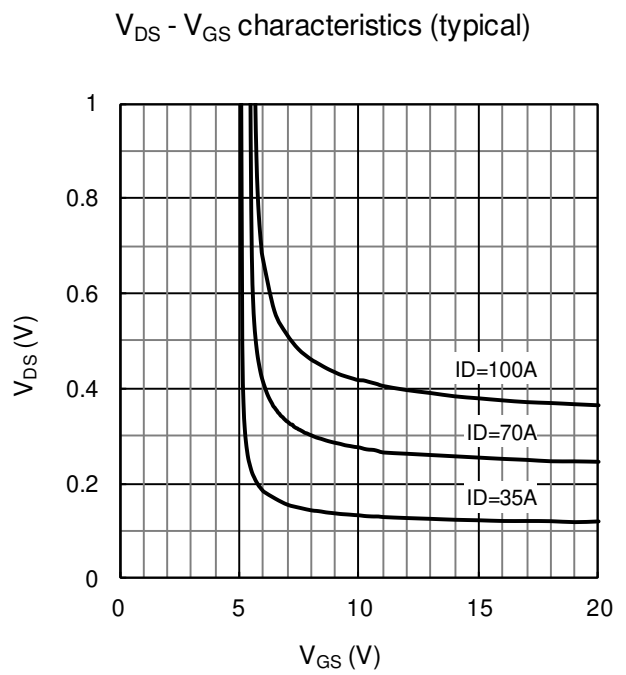
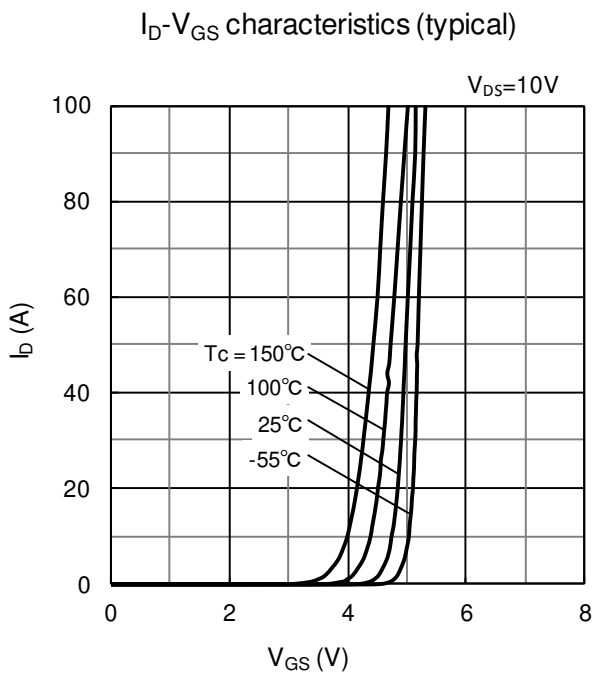
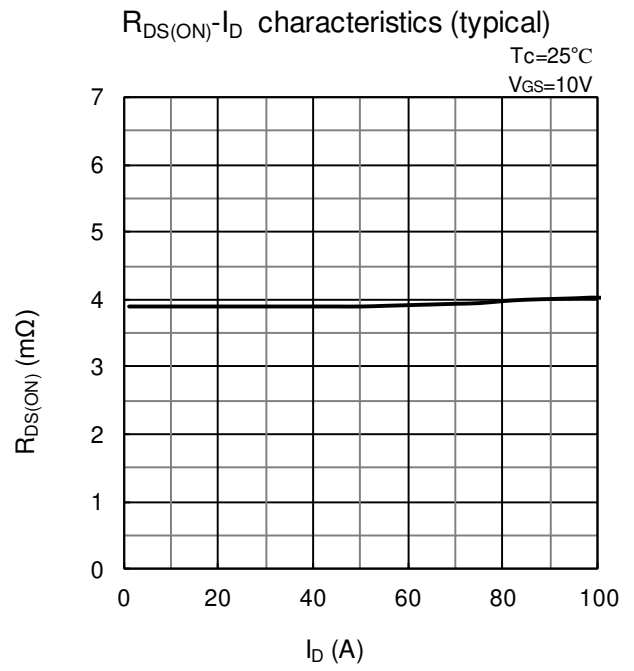
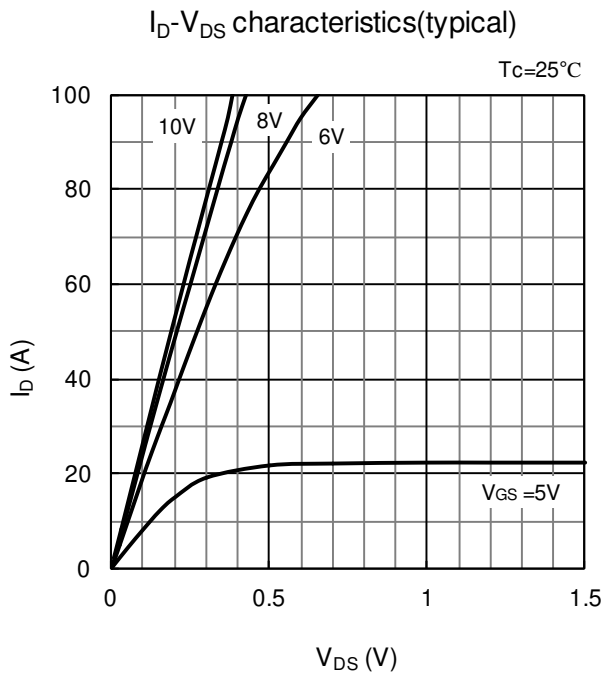
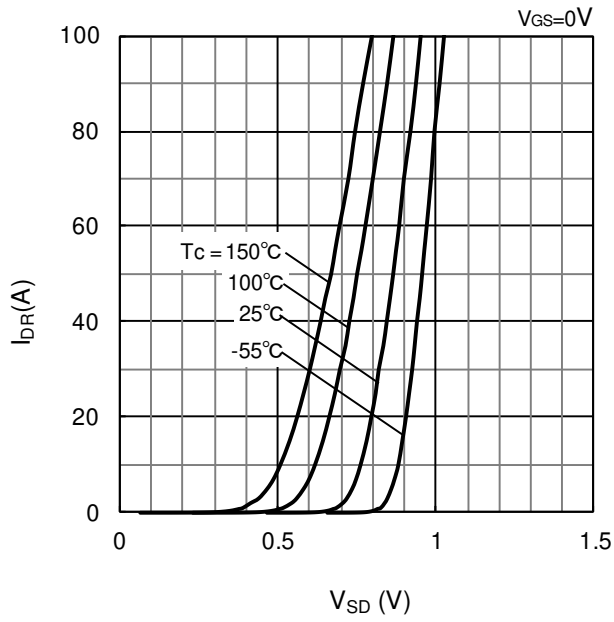


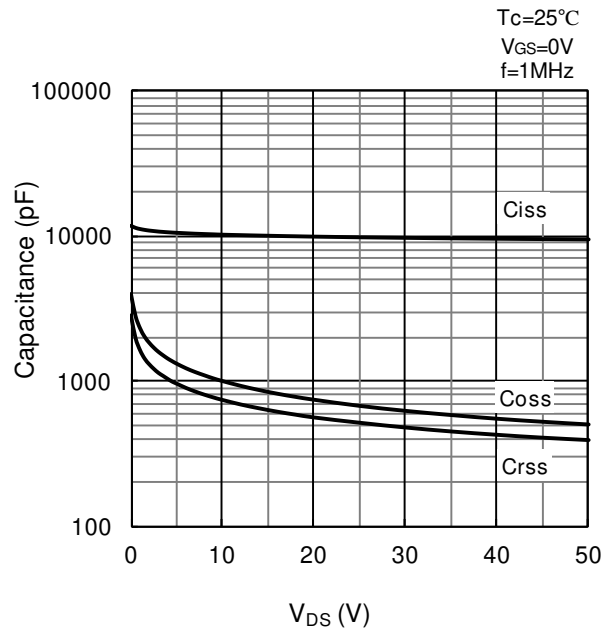
Figure 3 Diode Reverse Recovery Time



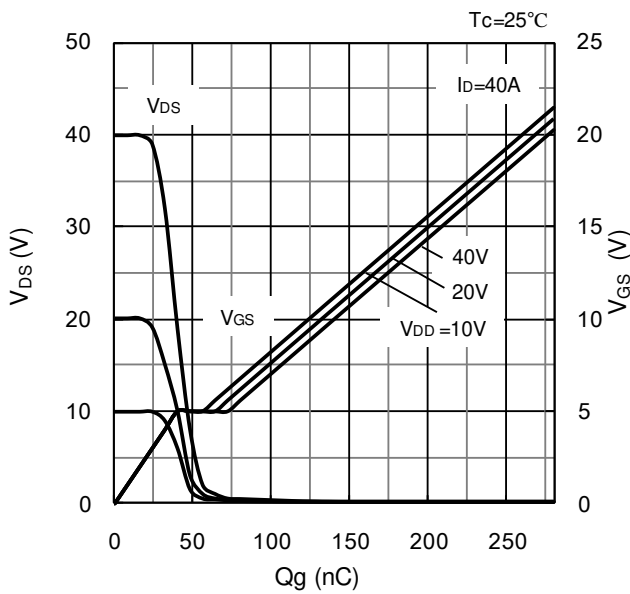
I_{DR} - V_{SD} characteristics (typical)



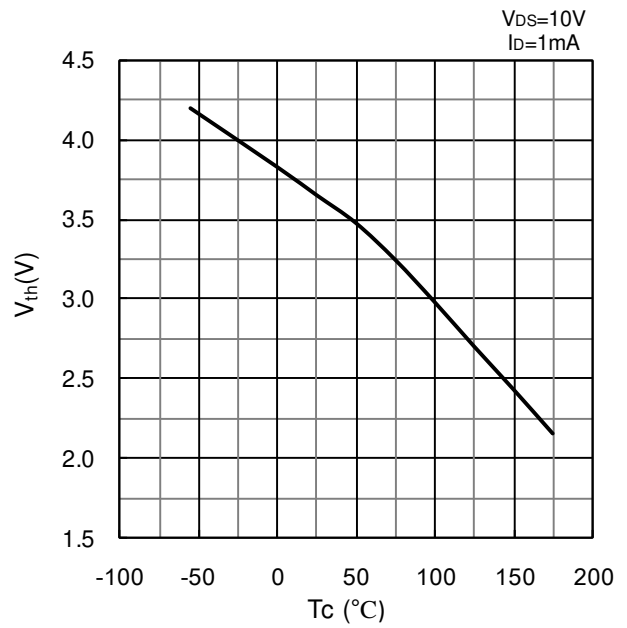
Capacitance- V_{DS} characteristics (typical)

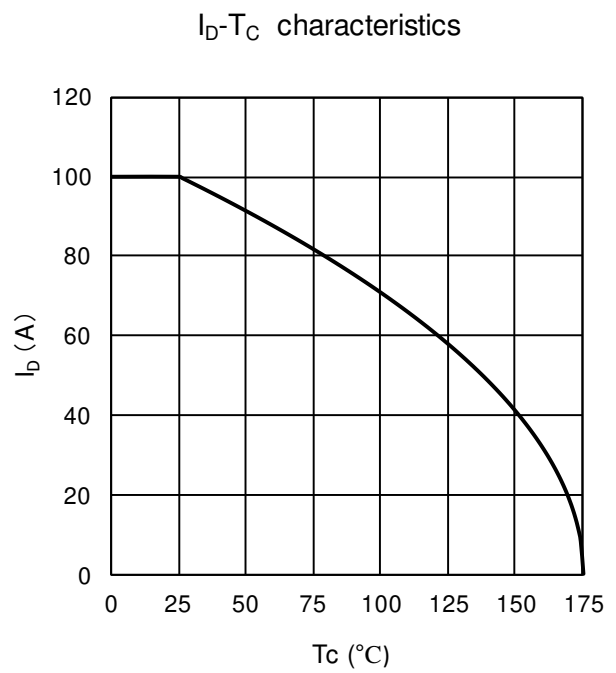
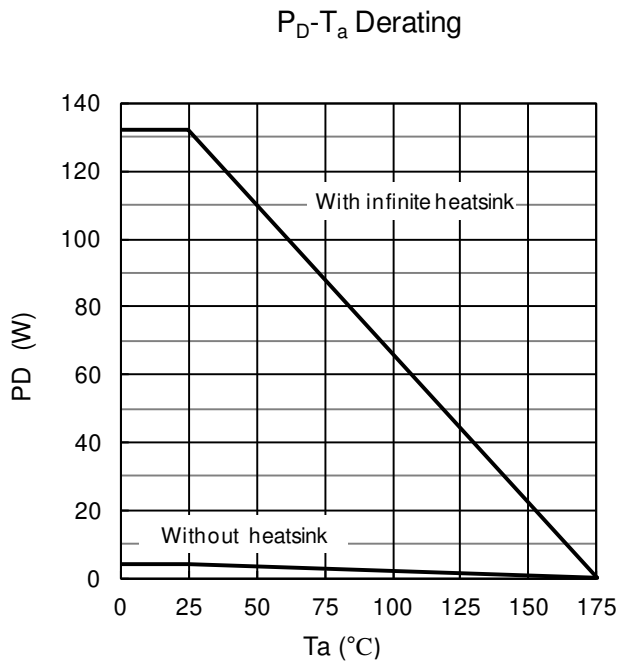
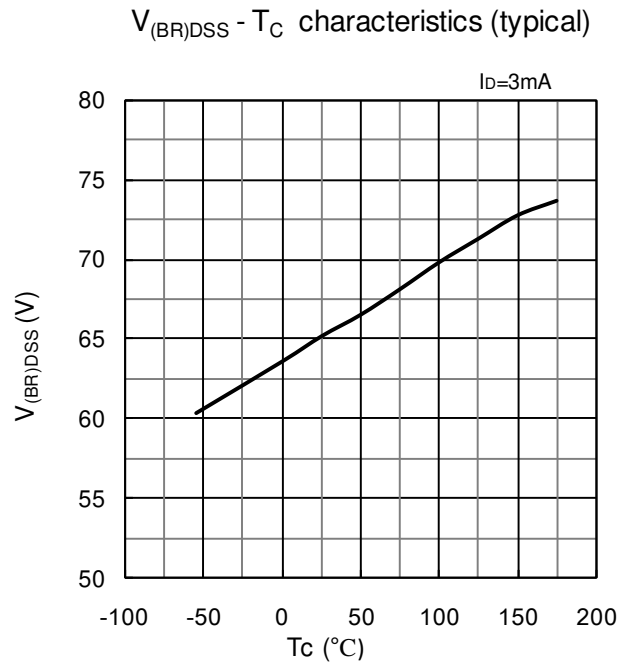
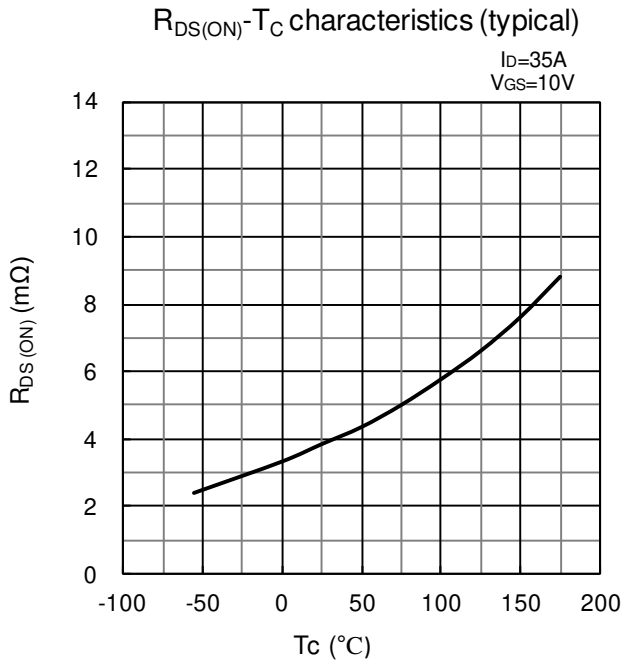


V_{GS} - Q_g characteristics (typical)

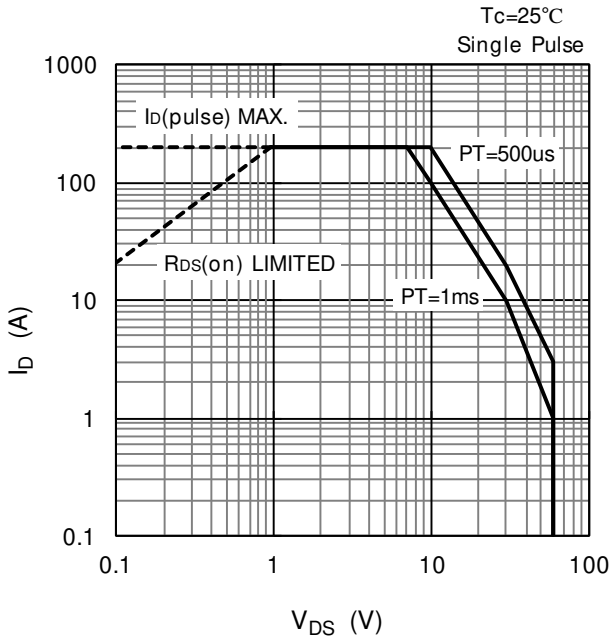


V_{th} - T_C characteristics (typical)

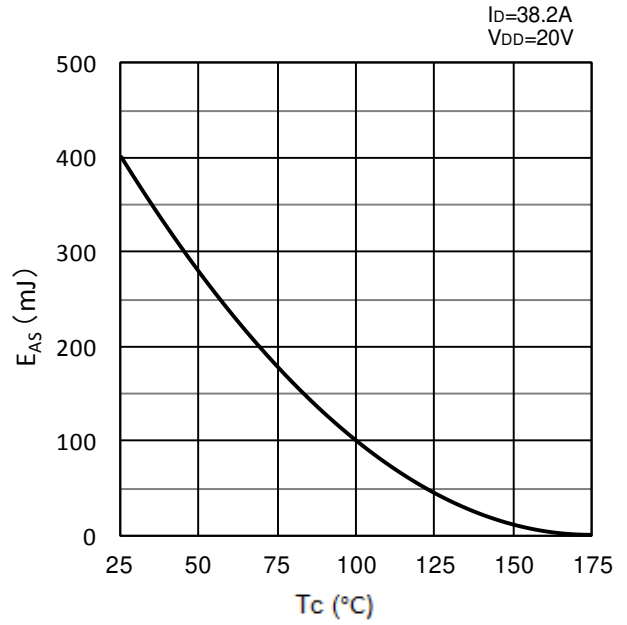




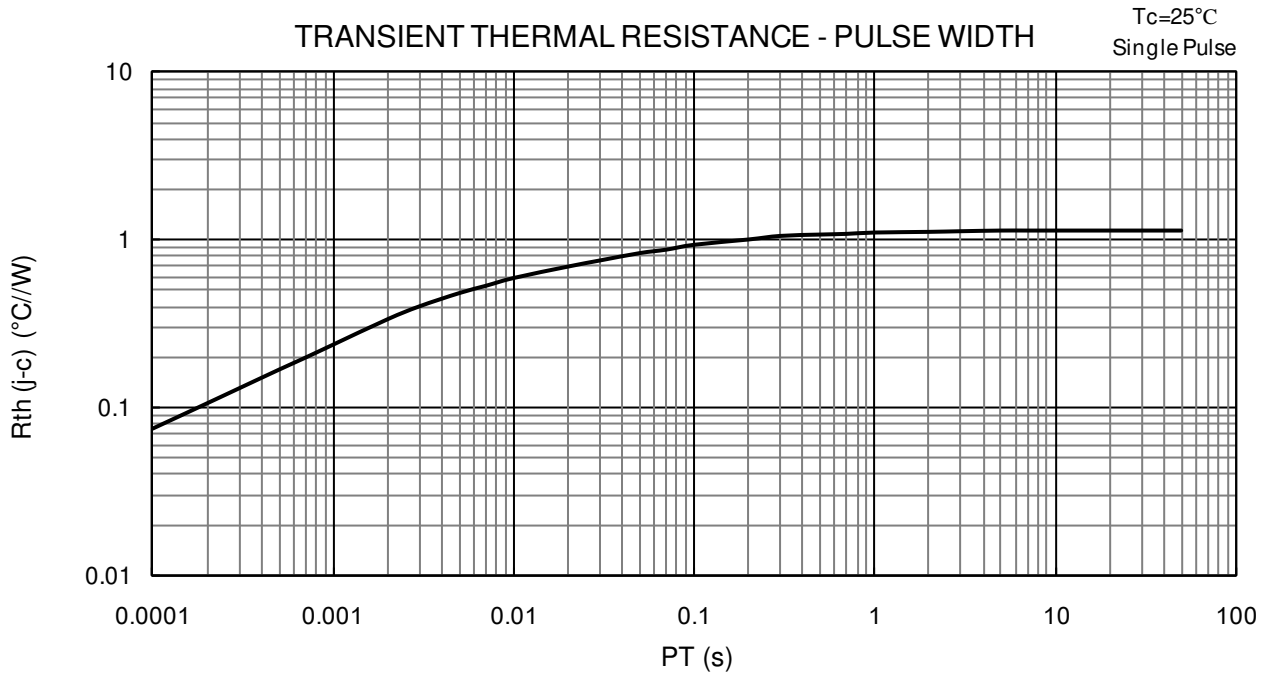
SAFE OPERATING AREA



E_{AS}-T_c characteristics



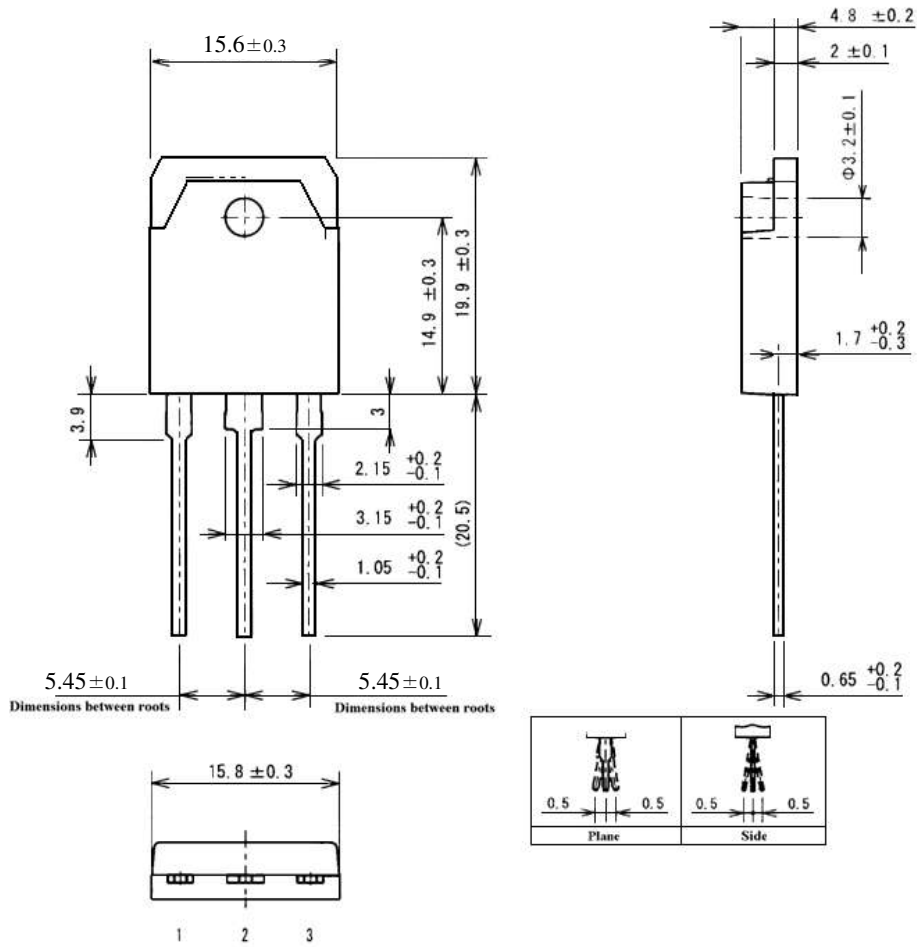
TRANSIENT THERMAL RESISTANCE - PULSE WIDTH



2SK4161D

Package Outline

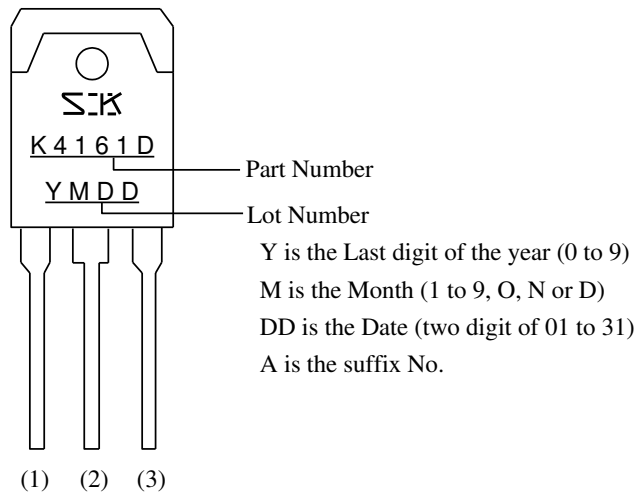
TO3P-3L



NOTES:

- Dimension is in millimeters
- Pin treatment Pb-free. Device composition compliant with the RoHS directive.

Marking Diagram



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